

**500mA LOW NOISE LDO REGULATOR****AP2213****General Description**

The AP2213 is a 500mA output current fixed voltage regulator which provides low noise, very low dropout voltage (typically 350mV at 500mA), very low standby current (1 μ A maximum) and excellent power supply ripple rejection (PSRR 75dB at 100Hz) in battery powered applications, such as handsets and PDAs and in noise sensitive applications, such as RF electronics.

The AP2213 features individual logic compatible enable/shutdown control inputs, a low power shutdown mode for extended battery life, over current protection, over temperature protection, as well as reversed-battery protection.

The AP2213 has 2.5V, 3.0V and 3.3V versions.

The AP2213 is available in TO-252-2 (1), SOIC-8 and SOT-223 packages.

Features

- Up to 500mA Output Current
- Low Standby Current
- Low Dropout Voltage: $V_{DROP}=350\text{mV}$ at 500mA
- High Output Accuracy: $\pm 1\%$
- Good Ripple Rejection Ability: 75dB at 100Hz and $I_{OUT}=100\mu\text{A}$
- Tight Load and Line Regulation
- Low Temperature Coefficient
- Over Current Protection
- Thermal Protection
- Reversed-battery Protection
- Logic-controlled Enable

Applications

- Laptop, Notebook, and Palmtop Computer
- CD-ROM, CD-R/RW, DVD Driver
- Portable Electronic
- PC Peripheral



Figure 1. Package Types of AP2213



500mA LOW NOISE LDO REGULATOR

AP2213

Pin Configuration

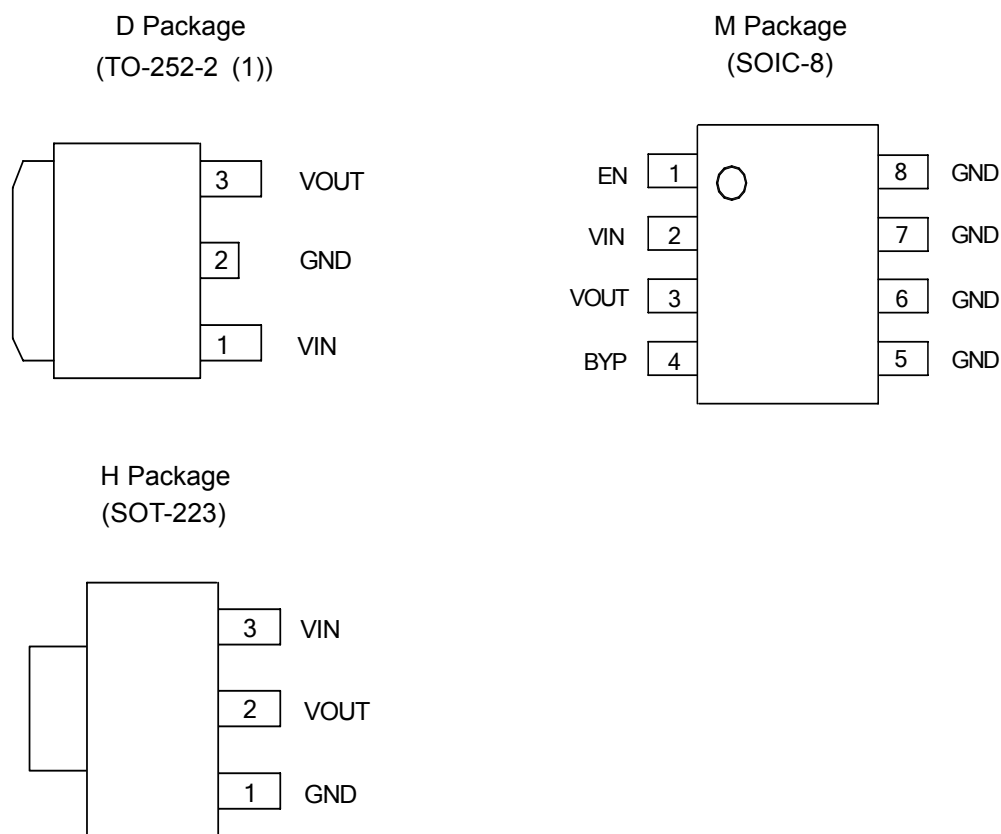


Figure 2. Pin Configuration of AP2213 (Top View)

Pin Description

Pin Number			Pin Name	Function
TO-252-2 (1)	SOIC-8	SOT-223		
3	3	2	VOUT	Regulated output voltage
2	5, 6, 7, 8	1	GND	Ground
1	2	3	VIN	Input Voltage
	1		EN	Enable input: CMOS or TTL compatible input. Logic high=enable, logic low=shutdown
	4		BYP	Bypass capacitor for low noise operation

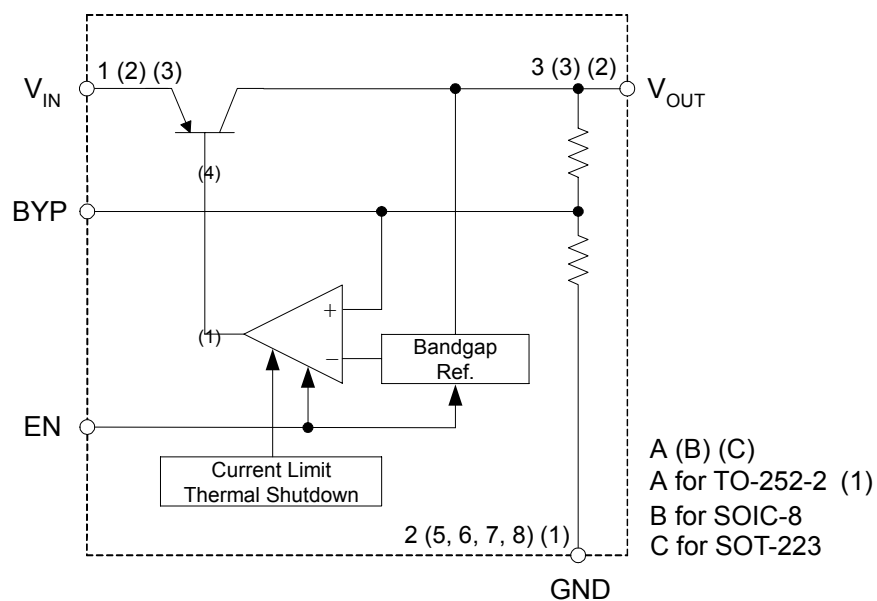
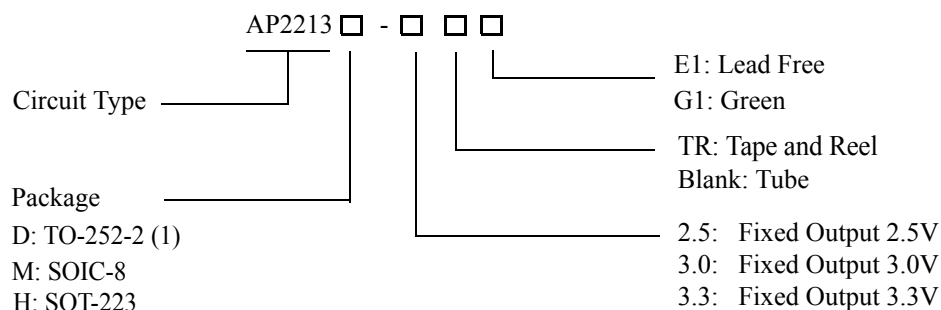
**500mA LOW NOISE LDO REGULATOR****AP2213****Functional Block Diagram**

Figure 3. Functional Block Diagram of AP2213

**500mA LOW NOISE LDO REGULATOR****AP2213****Ordering Information**

Package	Temperature Range	Part Number		Marking ID		Packing Type
		Lead Free	Green	Lead Free	Green	
TO-252-2 (1)	-40 to 125°C	AP2213D-2.5E1	AP2213D-2.5G1	AP2213D-2.5E1	AP2213D-2.5G1	Tube
		AP2213D-2.5TRE1	AP2213D-2.5TRG1	AP2213D-2.5E1	AP2213D-2.5G1	Tape & Reel
		AP2213D-3.0E1	AP2213D-3.0G1	AP2213D-3.0E1	AP2213D-3.0G1	Tube
		AP2213D-3.0TRE1	AP2213D-3.0TRG1	AP2213D-3.0E1	AP2213D-3.0G1	Tape & Reel
		AP2213D-3.3E1	AP2213D-3.3G1	AP2213D-3.3E1	AP2213D-3.3G1	Tube
		AP2213D-3.3TRE1	AP2213D-3.3TRG1	AP2213D-3.3E1	AP2213D-3.3G1	Tape & Reel
SOIC-8	-40 to 125°C	AP2213M-2.5E1	AP2213M-2.5G1	2213M-2.5E1	2213M-2.5G1	Tube
		AP2213M-2.5TRE1	AP2213M-2.5TRG1	2213M-2.5E1	2213M-2.5G1	Tape & Reel
		AP2213M-3.0E1	AP2213M-3.0G1	2213M-3.0E1	2213M-3.0G1	Tube
		AP2213M-3.0TRE1	AP2213M-3.0TRG1	2213M-3.0E1	2213M-3.0G1	Tape & Reel
		AP2213M-3.3E1	AP2213M-3.3G1	2213M-3.3E1	2213M-3.3G1	Tube
		AP2213M-3.3TRE1	AP2213M-3.3TRG1	2213M-3.3E1	2213M-3.3G1	Tape & Reel
SOT-223	-40 to 125°C	AP2213H-2.5TRE1	AP2213H-2.5TRG1	EH13C	GH13C	Tape & Reel
		AP2213H-3.0TRE1	AP2213H-3.0TRG1	EH13E	GH13E	Tape & Reel
		AP2213H-3.3TRE1	AP2213H-3.3TRG1	EH13F	GH13F	Tape & Reel

BCD Semiconductor's Pb-free products, as designated with "E1" suffix in the part number, are RoHS compliant. Products with "G1" suffix are available in green packages.

**500mA LOW NOISE LDO REGULATOR****AP2213****Absolute Maximum Ratings (Note 1)**

Parameter	Symbol	Value		Unit
Supply Input Voltage	V_{IN}	20		V
Enable Input Voltage	V_{EN}	20		V
Power Dissipation	P_D	Internally Limited (Thermal Protection)		W
Lead Temperature (Soldering, 10sec)	T_{LEAD}	260		°C
Junction Temperature	T_J	150		°C
Storage Temperature	T_{STG}	-65 to 150		°C
ESD (Machine Model)	ESD	300		V
Thermal Resistance (No Heatsink)	θ_{JA}	TO-252-2 (1)	90	°C/W
		SOIC-8	160	
		SOT-223	108	

Note 1: Stresses greater than those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "Recommended Operating Conditions" is not implied. Exposure to "Absolute Maximum Ratings" for extended periods may affect device reliability.

Recommended Operating Conditions

Parameter	Symbol	Min	Max	Unit
Supply Input Voltage	V_{IN}	2.5	18	V
Enable Input Voltage	V_{EN}	0	18	V
Operating Junction Temperature	T_J	-40	125	°C


500mA LOW NOISE LDO REGULATOR
AP2213
Electrical Characteristics
AP2213-2.5 Electrical Characteristics

$V_{IN}=3.5V$, $I_{OUT}=100\mu A$, $C_{IN}=1.0\mu F$, $C_{OUT}=2.2\mu F$, $V_{EN}\geq 2.0V$, $T_J=25^\circ C$, **Bold** typeface applies over $-40^\circ C\leq T_J\leq 125^\circ C$ (Note 2), unless otherwise specified.

Parameter	Symbol	Conditions	Min	Typ	Max	Unit
Output Voltage Accuracy	$\Delta V_{OUT}/V_{OUT}$	Variation from specified V_{OUT}	-1		1	%
			-2		2	
Output Voltage Temperature Coefficient (Note 3)	$\Delta V_{OUT}/\Delta T$			120		$\mu V/^\circ C$
	$(\Delta V_{OUT}/V_{OUT})/\Delta T$			48		ppm/ $^\circ C$
Line Regulation	V_{RLINE}	$V_{IN}=3.5V$ to $13.2V$		1.5	4.5	mV
					12	
Load Regulation (Note 4)	V_{RLOAD}	$I_{OUT}=0.1mA$ to $500mA$		1	7	mV
					17	
Dropout Voltage (Note 5)	V_{DROP}	$I_{OUT}=100\mu A$		15	50	mV
					70	
		$I_{OUT}=50mA$		110	150	
					230	
		$I_{OUT}=100mA$		140	250	
					300	
		$I_{OUT}=150mA$		165	275	
					350	
		$I_{OUT}=300mA$		250	400	
					500	
		$I_{OUT}=500mA$		350	600	
					700	
Standby Current	I_{STD}	$V_{EN}\leq 0.4V$ (shutdown)		0.01	1	μA
		$V_{EN}\leq 0.18V$ (shutdown)			5	
Ground Pin Current (Note 6)	I_{GND}	$V_{EN}\geq 2.0V$, $I_{OUT}=100\mu A$		100	150	μA
					180	
		$V_{EN}\geq 2.0V$, $I_{OUT}=50mA$		350	600	
					800	
		$V_{EN}\geq 2.0V$, $I_{OUT}=150mA$		1.3	1.9	mA
					2.5	
		$V_{EN}\geq 2.0V$, $I_{OUT}=300mA$		4	10	
					15	
		$V_{EN}\geq 2.0V$, $I_{OUT}=500mA$		11	20	
					28	

**500mA LOW NOISE LDO REGULATOR****AP2213****Electrical Characteristics (Continued)****AP2213-2.5 Electrical Characteristics**

$V_{IN}=3.5V$, $I_{OUT}=100\mu A$, $C_{IN}=1.0\mu F$, $C_{OUT}=2.2\mu F$, $V_{EN}\geq 2.0V$, $T_J=25^\circ C$, **Bold** typeface applies over $-40^\circ C\leq T_J\leq 125^\circ C$ (Note 2), unless otherwise specified.

Parameter	Symbol	Conditions	Min	Typ	Max	Unit
Ripple Rejection	PSRR	$f=100Hz$, $I_{OUT}=100\mu A$		75		dB
Current Limit	I_{LIMIT}	$V_{OUT}=0V$		700	1000	mA
Output Noise	e_{no}	$I_{OUT}=50mA$, $C_{OUT}=2.2\mu F$, 100pF from BYP to GND		260		$nV/\sqrt{Hz}$
Enable Input Logic-low Voltage	V_{IL}	Regulator shutdown			0.4	V
					0.18	
Enable Input Logic-high Voltage	V_{IH}	Regulator enabled	2.0			V
Enable Input Logic-low Current	I_{IL}	$V_{IL}\leq 0.4V$		0.01	1	μA
		$V_{IL}\leq 0.18V$			2	
Enable Input Logic-high Current	I_{IH}	$V_{IL}\geq 2.0V$		5	20	μA
		$V_{IL}\geq 2.0V$			25	
Thermal Resistance	θ_{JC}	TO-252-2 (1)		20		$^\circ C/W$
		SOIC-8		45		
		SOT-223		31		

Note 2: Specifications in bold type are limited to $-40^\circ C\leq T_J\leq 125^\circ C$. Limits over temperature are guaranteed by design, but not tested in production.

Note 3: Output voltage temperature coefficient is defined as the worst case voltage change divided by the total temperature range.

Note 4: Regulation is measured at constant junction temperature using low duty cycle pulse testing. Parts are tested for load regulation in the load range from 0.1mA to 500mA. Changes in output voltage due to heating effects are covered by the thermal regulation specification.

Note 5: Dropout voltage is defined as the input to output differential at which the output voltage drops 1% ($T_J=25^\circ C$) or 2% ($-40^\circ C\leq T_J\leq 125^\circ C$) below its nominal value measured at 1V differential.

Note 6: Ground pin current is the regulator quiescent current plus pass transistor base current. The total current drawn from the


500mA LOW NOISE LDO REGULATOR
AP2213
Electrical Characteristics (Continued)
AP2213-3.0 Electrical Characteristics

$V_{IN}=4V$, $I_{OUT}=100\mu A$, $C_{IN}=1.0\mu F$, $C_{OUT}=2.2\mu F$, $V_{EN}\geq 2.0V$, $T_J=25^\circ C$, **Bold** typeface applies over $-40^\circ C\leq T_J\leq 125^\circ C$ (Note 2), unless otherwise specified.

Parameter	Symbol	Conditions	Min	Typ	Max	Unit
Output Voltage Accuracy	$\Delta V_{OUT}/V_{OUT}$	Variation from specified V_{OUT}	-1		1	%
			-2		2	
Output Voltage Temperature Coefficient (Note 3)	$\Delta V_{OUT}/\Delta T$			120		$\mu V/^\circ C$
	$(\Delta V_{OUT}/V_{OUT})/\Delta T$			40		ppm/ $^\circ C$
Line Regulation	V_{RLINE}	$V_{IN}=4V$ to 13.2V		1.5	4.5	mV
					12	
Load Regulation (Note 4)	V_{RLOAD}	$I_{OUT}=0.1mA$ to 500mA		1	8	mV
					17	
Dropout Voltage (Note 5)	V_{DROP}	$I_{OUT}=100\mu A$		15	50	mV
					70	
		$I_{OUT}=50mA$		110	150	
					230	
		$I_{OUT}=100mA$		140	250	
					300	
		$I_{OUT}=150mA$		165	275	
					350	
		$I_{OUT}=300mA$		250	400	
					500	
		$I_{OUT}=500mA$		350	600	
					700	
Standby Current	I_{STD}	$V_{EN}\leq 0.4V$ (shutdown)		0.01	1	μA
		$V_{EN}\leq 0.18V$ (shutdown)			5	
Ground Pin Current (Note 6)	I_{GND}	$V_{EN}\geq 2.0V$, $I_{OUT}=100\mu A$		100	150	μA
					180	
		$V_{EN}\geq 2.0V$, $I_{OUT}=50mA$		350	600	
					800	mA
		$V_{EN}\geq 2.0V$, $I_{OUT}=150mA$		1.3	1.9	
					2.5	
		$V_{EN}\geq 2.0V$, $I_{OUT}=300mA$		4	10	
					15	
		$V_{EN}\geq 2.0V$, $I_{OUT}=500mA$		11	20	
					28	


500mA LOW NOISE LDO REGULATOR
AP2213
Electrical Characteristics (Continued)
AP2213-3.0 Electrical Characteristics

$V_{IN}=4V$, $I_{OUT}=100\mu A$, $C_{IN}=1.0\mu F$, $C_{OUT}=2.2\mu F$, $V_{EN}\geq 2.0V$, $T_J=25^\circ C$, **Bold** typeface applies over $-40^\circ C\leq T_J\leq 125^\circ C$ (Note 2), unless otherwise specified.

Parameter	Symbol	Conditions	Min	Typ	Max	Unit
Ripple Rejection	PSRR	$f=100Hz$, $I_{OUT}=100\mu A$		75		dB
Current Limit	I_{LIMIT}	$V_{OUT}=0V$		700	1000	mA
Output Noise	e_{no}	$I_{OUT}=50mA$, $C_{OUT}=2.2\mu F$, 100pF from BYP to GND		260		$nV/\sqrt{Hz}$
Enable Input Logic-low Voltage	V_{IL}	Regulator shutdown			0.4	V
					0.18	
Enable Input Logic-high Voltage	V_{IH}	Regulator enabled	2.0			V
Enable Input Logic-low Current	I_{IL}	$V_{IL}\leq 0.4V$		0.01	1	μA
		$V_{IL}\leq 0.18V$			2	
Enable Input Logic-high Current	I_{IH}	$V_{IL}\geq 2.0V$		5	20	μA
		$V_{IL}\geq 2.0V$			25	
Thermal Resistance	θ_{JC}	TO-252-2 (1)		20		$^\circ C/W$
		SOIC-8		45		
		SOT-223		31		

Note 2: Specifications in bold type are limited to $-40^\circ C\leq T_J\leq 125^\circ C$. Limits over temperature are guaranteed by design, but not tested in production.

Note 3: Output voltage temperature coefficient is defined as the worst case voltage change divided by the total temperature range.

Note 4: Regulation is measured at constant junction temperature using low duty cycle pulse testing. Parts are tested for load regulation in the load range from 0.1mA to 500mA. Changes in output voltage due to heating effects are covered by the thermal regulation specification.

Note 5: Dropout voltage is defined as the input to output differential at which the output voltage drops 1% ($T_J=25^\circ C$) or 2% ($-40^\circ C\leq T_J\leq 125^\circ C$) below its nominal value measured at 1V differential.

Note 6: Ground pin current is the regulator quiescent current plus pass transistor base current. The total current drawn from the supply is the sum of the load current plus the ground pin current.


500mA LOW NOISE LDO REGULATOR
AP2213
Electrical Characteristics (Continued)
AP2213-3.3 Electrical Characteristics

$V_{IN}=4.3V$, $I_{OUT}=100\mu A$, $C_{IN}=1.0\mu F$, $C_{OUT}=2.2\mu F$, $V_{EN}\geq 2.0V$, $T_J=25^\circ C$, **Bold** typeface applies over $-40^\circ C\leq T_J\leq 125^\circ C$ (Note 2), unless otherwise specified.

Parameter	Symbol	Conditions	Min	Typ	Max	Unit
Output Voltage Accuracy	$\Delta V_{OUT}/V_{OUT}$	Variation from specified V_{OUT}	-1		1	%
			-2		2	
Output Voltage Temperature Coefficient (Note 3)	$\Delta V_{OUT}/\Delta T$			120		$\mu V/^\circ C$
	$(\Delta V_{OUT}/V_{OUT})/\Delta T$			36.3		ppm/ $^\circ C$
Line Regulation	V_{RLINE}	$V_{IN}=4.3V$ to $13.2V$		1.5	4.5	mV
					12	
Load Regulation (Note 4)	V_{RLOAD}	$I_{OUT}=0.1mA$ to $500mA$		1	9	mV
					18	
Dropout Voltage (Note 5)	V_{DROP}	$I_{OUT}=100\mu A$		15	50	mV
					70	
		$I_{OUT}=50mA$		110	150	
					230	
		$I_{OUT}=100mA$		140	250	
					300	
		$I_{OUT}=150mA$		165	275	
					350	
		$I_{OUT}=300mA$		250	400	
					500	
		$I_{OUT}=500mA$		350	600	
					700	
Standby Current	I_{STD}	$V_{EN}\leq 0.4V$ (shutdown)		0.01	1	μA
		$V_{EN}\leq 0.18V$ (shutdown)			5	
Ground Pin Current (Note 6)	I_{GND}	$V_{EN}\geq 2.0V$, $I_{OUT}=100\mu A$		100	150	μA
					180	
		$V_{EN}\geq 2.0V$, $I_{OUT}=50mA$		350	600	
					800	
		$V_{EN}\geq 2.0V$, $I_{OUT}=150mA$		1.3	1.9	mA
					2.5	
		$V_{EN}\geq 2.0V$, $I_{OUT}=300mA$		4	10	
					15	
		$V_{EN}\geq 2.0V$, $I_{OUT}=500mA$		11	20	
					28	

**500mA LOW NOISE LDO REGULATOR****AP2213****Electrical Characteristics (Continued)****AP2213-3.3 Electrical Characteristics**

$V_{IN}=4.3V$, $I_{OUT}=100\mu A$, $C_{IN}=1.0\mu F$, $C_{OUT}=2.2\mu F$, $V_{EN}\geq 2.0V$, $T_J=25^\circ C$, **Bold** typeface applies over $-40^\circ C\leq T_J\leq 125^\circ C$ (Note 2), unless otherwise specified.

Parameter	Symbol	Conditions	Min	Typ	Max	Unit
Ripple Rejection	PSRR	$f=100Hz$, $I_{OUT}=100\mu A$		75		dB
Current Limit	I_{LIMIT}	$V_{OUT}=0V$		700	1000	mA
Output Noise	e_{no}	$I_{OUT}=50mA$, $C_{OUT}=2.2\mu F$, 100pF from BYP to GND		260		$nV/\sqrt{Hz}$
Enable Input Logic-low Voltage	V_{IL}	Regulator shutdown			0.4	V
					0.18	
Enable Input Logic-high Voltage	V_{IH}	Regulator enabled	2.0			V
Enable Input Logic-low Current	I_{IL}	$V_{IL}\leq 0.4V$		0.01	1	μA
		$V_{IL}\leq 0.18V$			2	
Enable Input Logic-high Current	I_{IH}	$V_{IL}\geq 2.0V$		5	20	μA
		$V_{IL}\geq 2.0V$			25	
Thermal Resistance	θ_{JC}	TO-252-2 (1)		20		$^\circ C/W$
		SOIC-8		45		
		SOT-223		31		

Note 2: Specifications in bold type are limited to $-40^\circ C\leq T_J\leq 125^\circ C$. Limits over temperature are guaranteed by design, but not tested in production.

Note 3: Output voltage temperature coefficient is defined as the worst case voltage change divided by the total temperature range.

Note 4: Regulation is measured at constant junction temperature using low duty cycle pulse testing. Parts are tested for load regulation in the load range from 0.1mA to 500mA. Changes in output voltage due to heating effects are covered by the thermal regulation specification.

Note 5: Dropout voltage is defined as the input to output differential at which the output voltage drops 1% ($T_J=25^\circ C$) or 2% ($-40^\circ C\leq T_J\leq 125^\circ C$) below its nominal value measured at 1V differential.

Note 6: Ground pin current is the regulator quiescent current plus pass transistor base current. The total current drawn from the supply is the sum of the load current plus the ground pin current.

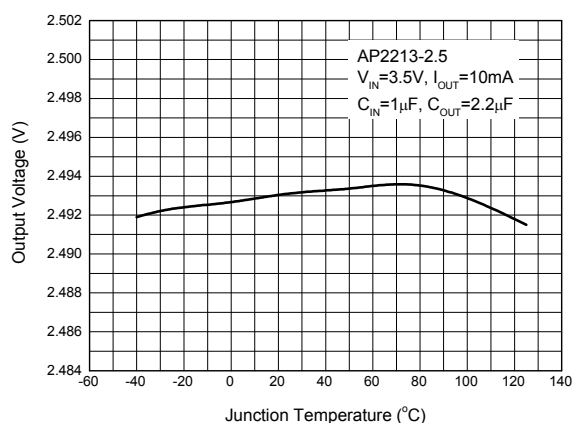
**500mA LOW NOISE LDO REGULATOR****AP2213****Typical Performance Characteristics**

Figure 4. Output Voltage vs. Junction Temperature

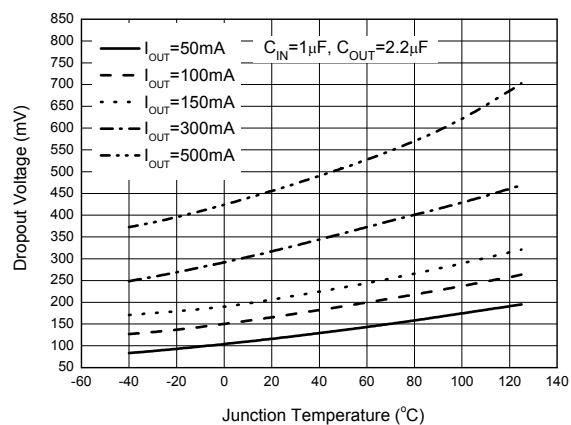


Figure 5. Dropout Voltage vs. Junction Temperature

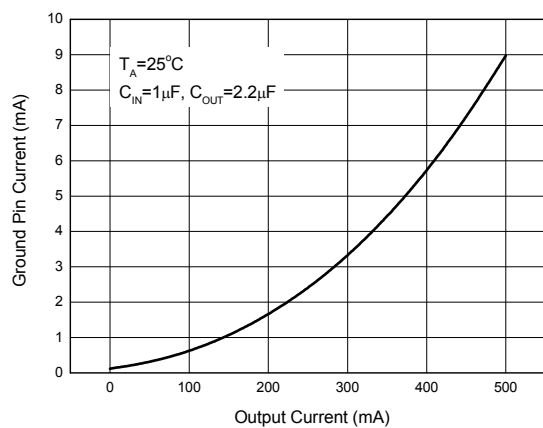


Figure 6. Ground Pin Current vs. Output Current

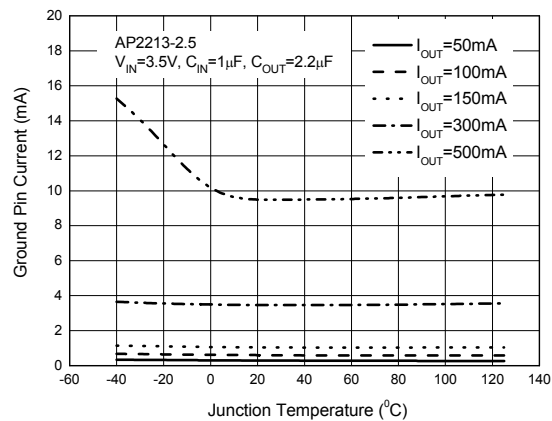


Figure 7. Ground Pin Current vs. Junction Temperature

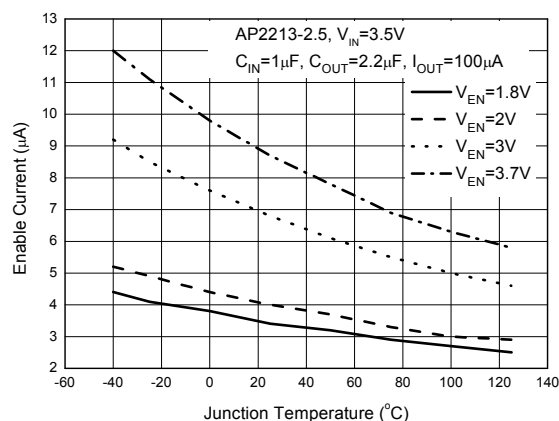
**500mA LOW NOISE LDO REGULATOR****AP2213****Typical Performance Characteristics (Continued)**

Figure 8. Enable Current vs. Junction Temperature

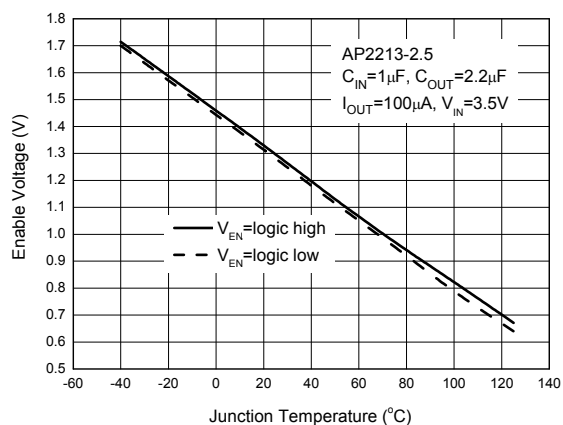


Figure 9. Enable Voltage vs. Junction Temperature

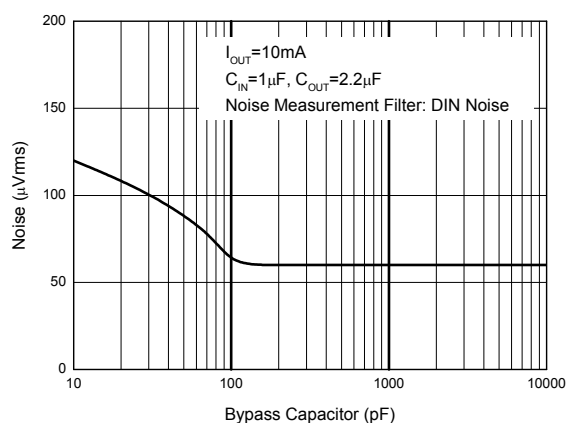


Figure 10. Noise vs. Bypass Capacitor

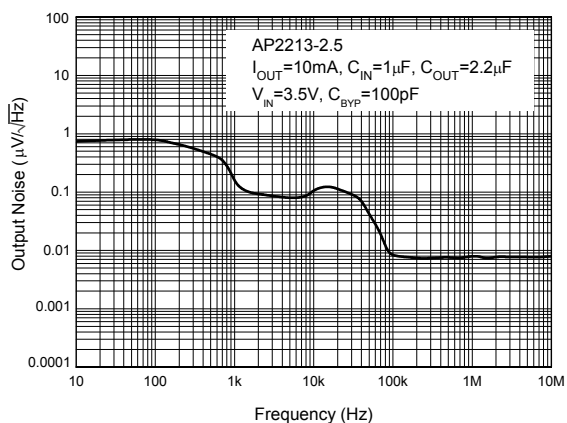
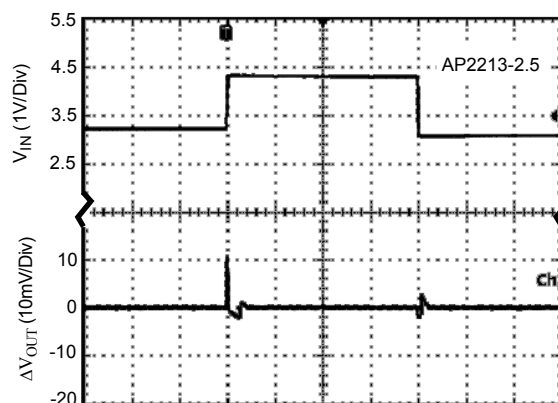


Figure 11. Output Noise vs. Frequency

**500mA LOW NOISE LDO REGULATOR****AP2213****Typical Performance Characteristics (Continued)**

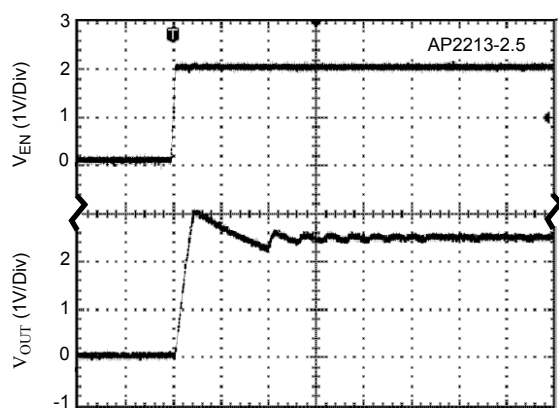
Time (200μs/Div)

Figure 12. Load Transient
(Conditions: $V_{IN}=3.5V$, $C_{BYP}=100pF$, $V_{EN}=2V$,
 $I_{OUT}=10$ to $500mA$, $C_{IN}=1μF$, $C_{OUT}=2.2μF$)



Time (200μs/Div)

Figure 13. Line Transient
(Conditions: $V_{IN}=3.4$ to $4.4V$, $V_{EN}=2V$, $I_{OUT}=100μA$,
 $C_{BYP}=100pF$, $C_{OUT}=2.2μF$)



Time (40μs/Div)

Figure 14. V_{EN} vs. V_{OUT}
(Conditions: $V_{EN}=0$ to $2V$, $V_{IN}=3.5V$, $I_{OUT}=30mA$,
 $C_{BYP}=open$, $C_{IN}=1μF$, $C_{OUT}=2.2μF$)

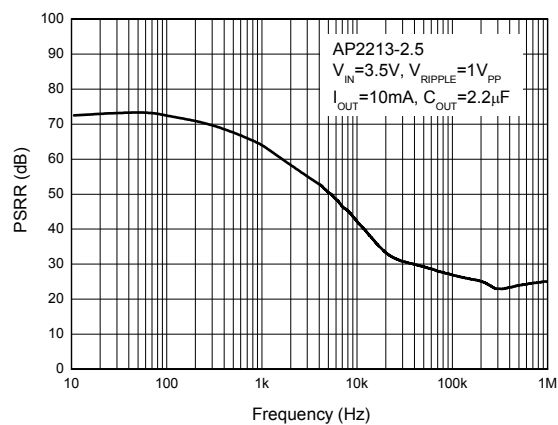


Figure 15. PSRR vs. Frequency

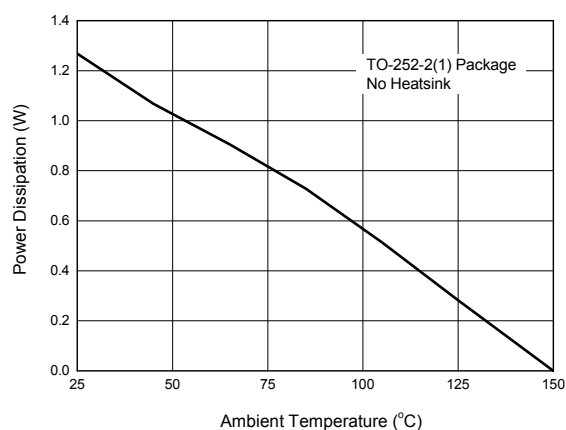
**500mA LOW NOISE LDO REGULATOR****AP2213****Typical Performance Characteristics (Continued)**

Figure 16. Power Dissipation vs. Ambient Temperature

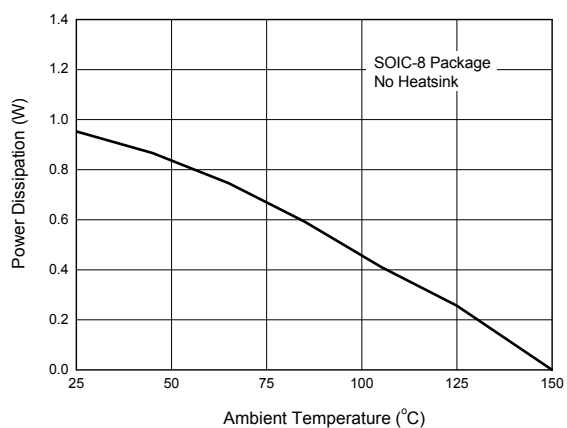


Figure 17. Power Dissipation vs. Ambient Temperature

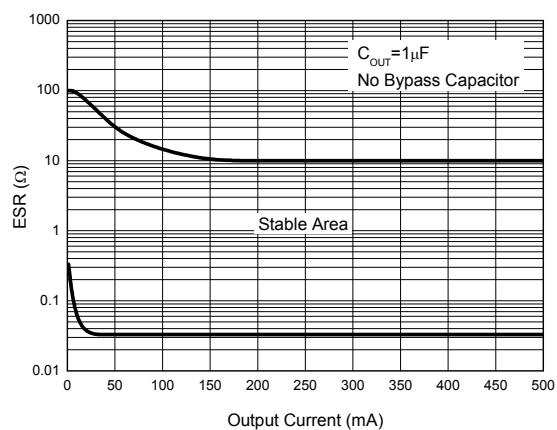


Figure 18. ESR vs. Output Current

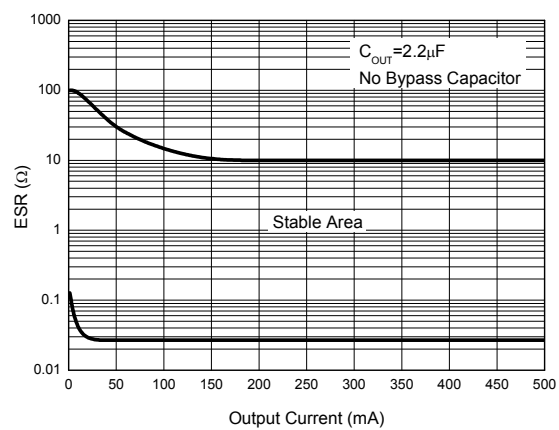


Figure 19. ESR vs. Output Current

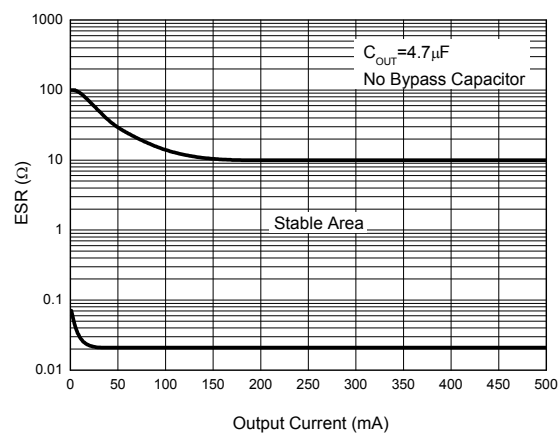
**500mA LOW NOISE LDO REGULATOR****AP2213****Typical Performance Characteristics (Continued)**

Figure 20. ESR vs. Output Current

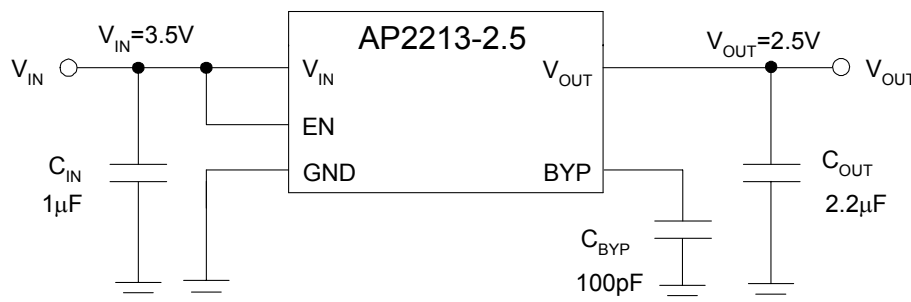
500mA LOW NOISE LDO REGULATOR**AP2213****Typical Application**

Figure 21. Typical Application of AP2213 (Note 7)

Note 7: Dropout voltage is 350mV when $T_A=25^\circ C$. In order to obtain a normal output voltage, $V_{OUT}+0.35V$ is the minimum input voltage which will results a low PSRR, imposing a bad influence on system. Therefore, the recommended input voltage is $V_{OUT}+1V$ to 18V. For AP2213-2.5 version, its input voltage can be set from 3.5V($V_{OUT}+1V$) to 18V.

**500mA LOW NOISE LDO REGULATOR****AP2213****Application Information****Input Capacitor**

A 1 μ F minimum capacitor is recommended to be placed between V_{IN} and GND.

Output Capacitor

It is required to prevent oscillation. 1 μ F minimum is recommended when C_{BYP} is unused. 2.2 μ F minimum is recommended when C_{BYP} is 100pF. The output capacitor may be increased to improve transient response.

Noise Bypass Capacitor

Bypass capacitor is connected to the internal voltage reference. A 100pF capacitor connected from BYP to GND make this reference quiet, resulting in a significant reduction in output noise, but the ESR stable area will be narrowed.

The start-up speed of the AP2213 is inversely proportional to the value of reference bypass capacitor. In some cases, if output noise is not a major concern and rapid turn-on is necessary, omit C_{BYP} and leave BYP open.

Power Dissipation

Thermal shutdown may take place if exceeding the maximum power dissipation in application. Under all possible operating conditions, the junction temperature must be within the range specified under absolute maximum ratings to avoid thermal shutdown.

To determine if the power dissipated in the regulator reaches the maximum power dissipation (see figure 16, 17), using:

$$T_J = P_D \cdot \theta_{JA} + T_A$$

$$P_D = (V_{IN} - V_{OUT}) \cdot I_{OUT} + V_{IN} \cdot I_{GND}$$

Where: $T_J \leq T_{J(max)}$, $T_{J(max)}$ is absolute maximum ratings for the junction temperature; $V_{IN} \cdot I_{GND}$ can be ignored due to its small value.

$T_{J(max)}$ is 150°C, θ_{JA} is 90°C/W for TO-252-2 (1) package and 160°C/W for SOIC-8 package.

Example: For 2.5V version packaged in SOIC-8, $I_{OUT}=500mA$, $T_A=50^\circ C$, $V_{IN(Max)}$ is:
 $(150^\circ C - 50^\circ C) / (0.5A \cdot 160^\circ C/W) + 2.5V = 3.75V$

Therefore, for good performance, please make sure that input voltage is less than 3.75V without heatsink when $T_A=50^\circ C$.

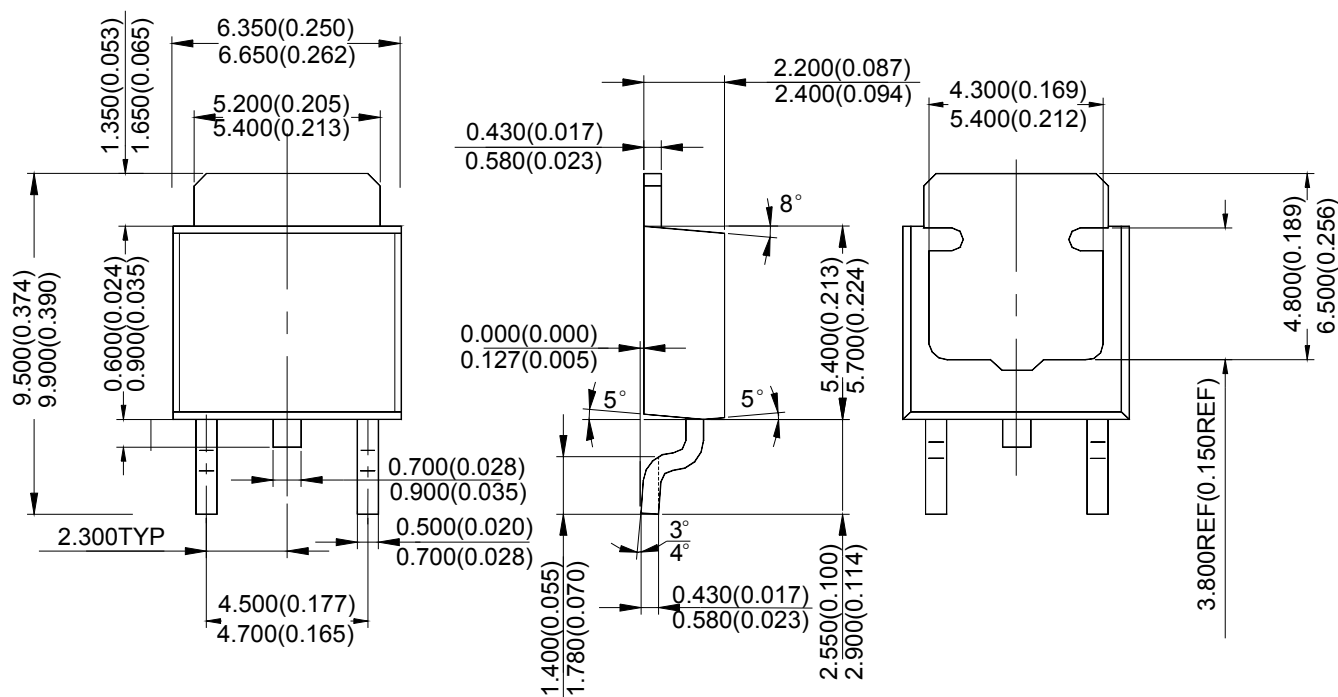
500mA LOW NOISE LDO REGULATOR

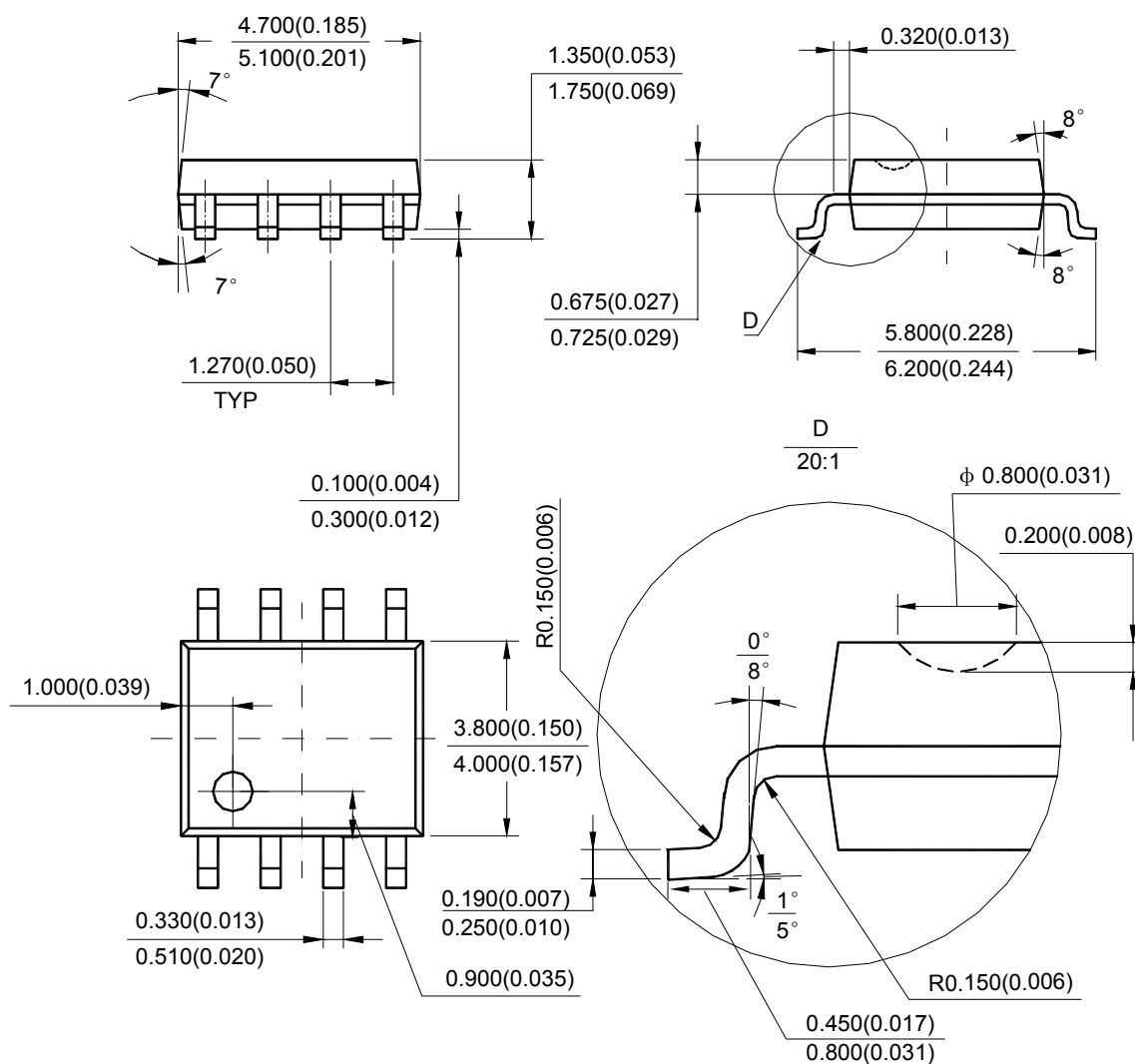
AP2213

Mechanical Dimensions

TO-252-2(1)

Unit: mm(inch)



500mA LOW NOISE LDO REGULATOR
AP2213
Mechanical Dimensions (Continued)
SOIC-8
Unit: mm(inch)


Note: Eject hole, oriented hole and mold mark is optional.



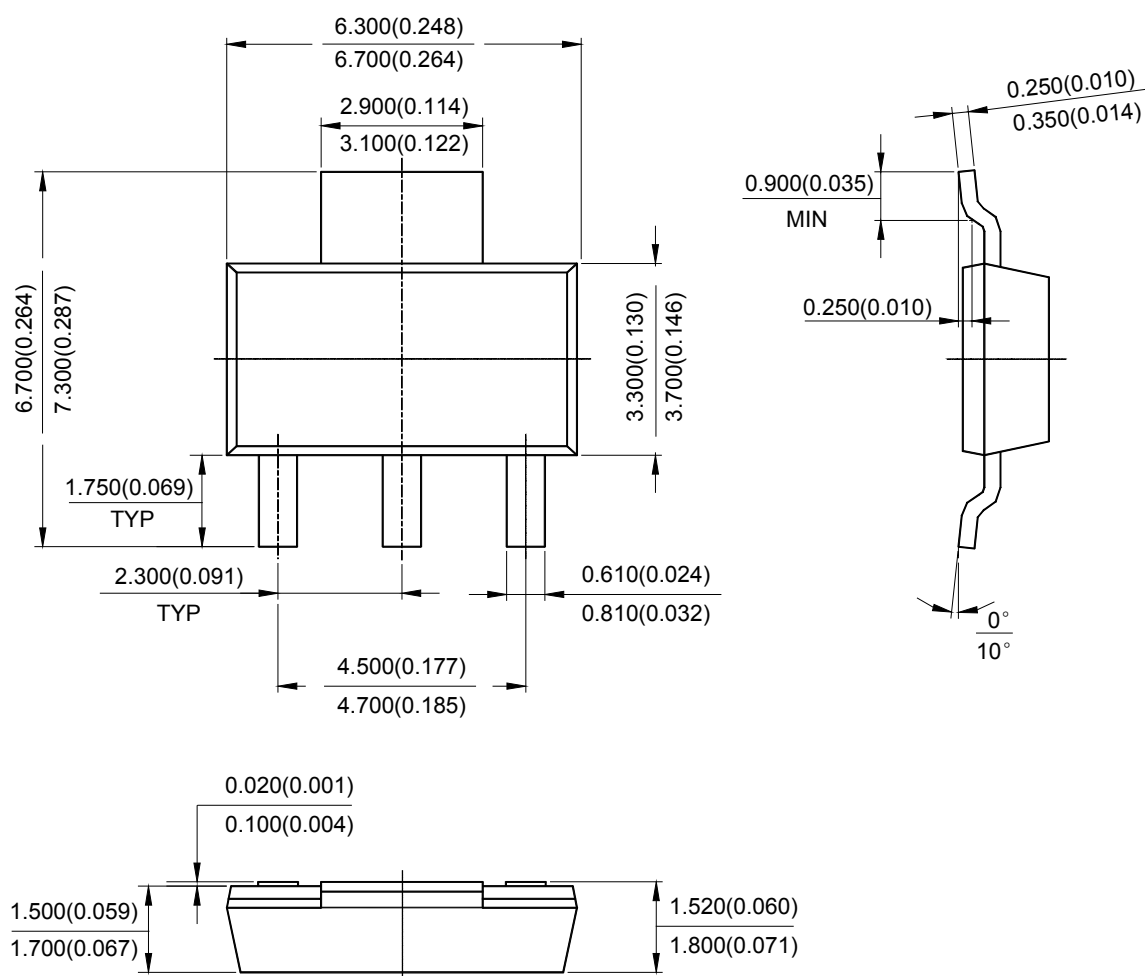
500mA LOW NOISE LDO REGULATOR

AP2213

Mechanical Dimensions (Continued)

SOT-223

Unit: mm(inch)





BCD Semiconductor Manufacturing Limited

<http://www.bcdsemi.com>

IMPORTANT NOTICE

BCD Semiconductor Manufacturing Limited reserves the right to make changes without further notice to any products or specifications herein. BCD Semiconductor Manufacturing Limited does not assume any responsibility for use of any its products for any particular purpose, nor does BCD Semiconductor Manufacturing Limited assume any liability arising out of the application or use of any its products or circuits. BCD Semiconductor Manufacturing Limited does not convey any license under its patent rights or other rights nor the rights of others.

MAIN SITE

- Headquarters

BCD Semiconductor Manufacturing Limited

No. 1600, Zi Xing Road, Shanghai ZiZhu Science-based Industrial Park, 200241, China
Tel: +86-21-24162266, Fax: +86-21-24162277

- Wafer Fab

Shanghai SIM-BCD Semiconductor Manufacturing Co., Ltd.

800 Yi Shan Road, Shanghai 200233, China
Tel: +86-21-6485 1491, Fax: +86-21-5450 0008

REGIONAL SALES OFFICE

Shenzhen Office

Shanghai SIM-BCD Semiconductor Manufacturing Co., Ltd., Shenzhen Office
Room E, 5F, Noble Center, No.1006, 3rd Fuzhong Road, Futian District, Shenzhen, 518026, China
Tel: +86-755-8826 7951
Fax: +86-755-8826 7865

Taiwan Office

BCD Semiconductor (Taiwan) Company Limited
4F, 298-1, Rui Guang Road, Nei-Hu District, Taipei, Taiwan
Tel: +886-2-2656 2808
Fax: +886-2-2656 2806

USA Office

BCD Semiconductor Corp.
30920 Huntwood Ave. Hayward, CA 94544, USA
Tel : +1-510-324-2988
Fax: +1-510-324-2788



Компания «ЭлектроПласт» предлагает заключение долгосрочных отношений при поставках импортных электронных компонентов на взаимовыгодных условиях!

Наши преимущества:

- Оперативные поставки широкого спектра электронных компонентов отечественного и импортного производства напрямую от производителей и с крупнейших мировых складов;
- Поставка более 17-ти миллионов наименований электронных компонентов;
- Поставка сложных, дефицитных, либо снятых с производства позиций;
- Оперативные сроки поставки под заказ (от 5 рабочих дней);
- Экспресс доставка в любую точку России;
- Техническая поддержка проекта, помощь в подборе аналогов, поставка прототипов;
- Система менеджмента качества сертифицирована по Международному стандарту ISO 9001;
- Лицензия ФСБ на осуществление работ с использованием сведений, составляющих государственную тайну;
- Поставка специализированных компонентов (Xilinx, Altera, Analog Devices, Intersil, Interpoint, Microsemi, Aeroflex, Peregrine, Syfer, Eurofarad, Texas Instrument, Miteq, Cobham, E2V, MA-COM, Hittite, Mini-Circuits, General Dynamics и др.);

Помимо этого, одним из направлений компании «ЭлектроПласт» является направление «Источники питания». Мы предлагаем Вам помощь Конструкторского отдела:

- Подбор оптимального решения, техническое обоснование при выборе компонента;
- Подбор аналогов;
- Консультации по применению компонента;
- Поставка образцов и прототипов;
- Техническая поддержка проекта;
- Защита от снятия компонента с производства.



Как с нами связаться

Телефон: 8 (812) 309 58 32 (многоканальный)

Факс: 8 (812) 320-02-42

Электронная почта: org@eplast1.ru

Адрес: 198099, г. Санкт-Петербург, ул. Калинина, дом 2, корпус 4, литера А.